

Ordering number : ENN7486

PNP Epitaxial Planar Silicon Transistors

**12A02SS**

Low-Frequency General-Purpose Amplifier Applications

Applications

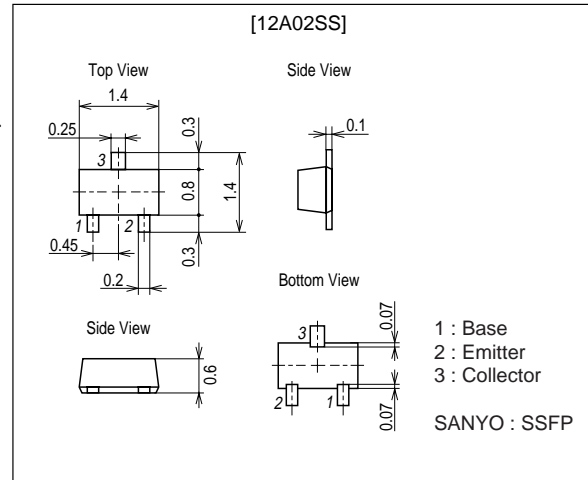
- Low-frequency Amplifier, high-speed switching, small motor drive, muting circuit.

Features

- Large current capacitance.
- Low collector-to-emitter saturation voltage (resistance).
RCE (sat) typ.=285mΩ [IC=1A, IB=50mA].
- Ultrasmall package facilitates miniaturization in end products.
- Small ON-resistance (Ron).

Package Dimensions

unit : mm
2159A



Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CB0}		-15	V
Collector-to-Emitter Voltage	V _{CEO}		-12	V
Emitter-to-Base Voltage	V _{EBO}		-5	V
Collector Current	I _C		-0.8	A
Collector Current (Pulse)	I _{CP}		-1.6	A
Collector Dissipation	P _C	Mounted on a glass-epoxy board (20X30X1.6mm)	200	mW
Junction Temperature	T _j		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I _{CB0}	V _{CB} = -12V, I _E =0			-100	nA
Emitter Cutoff Current	I _{EBO}	V _{EB} = -4V, I _C =0			-100	nA
DC Current Gain	h _{FE}	V _{CE} = -2V, I _C = -10mA	300		700	
Gain-Bandwidth Product	f _T	V _{CE} = -2V, I _C = -50mA		450		MHz

Marking : XK

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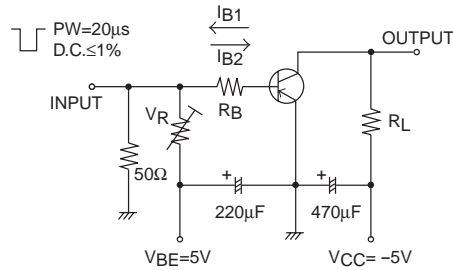
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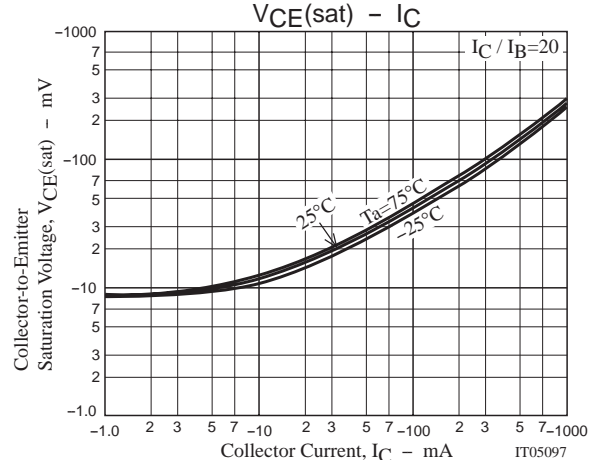
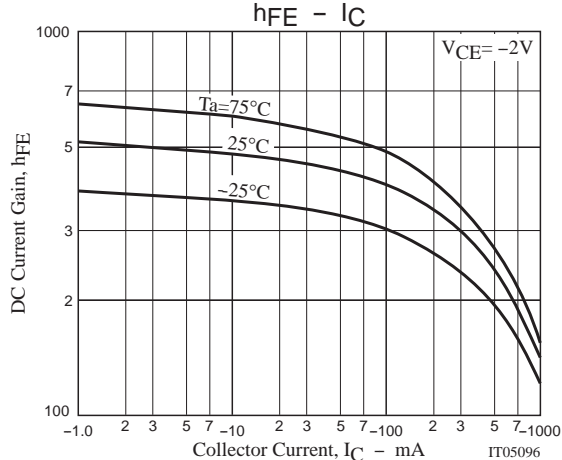
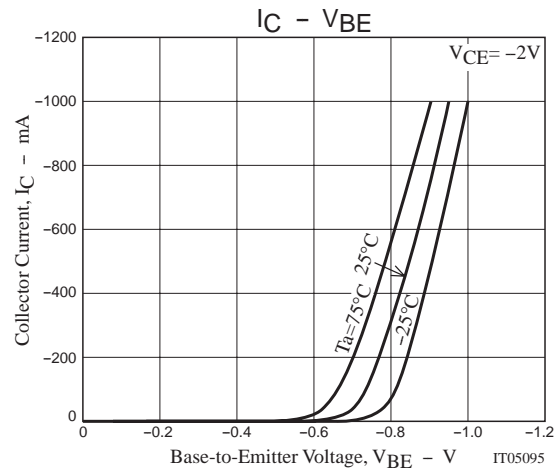
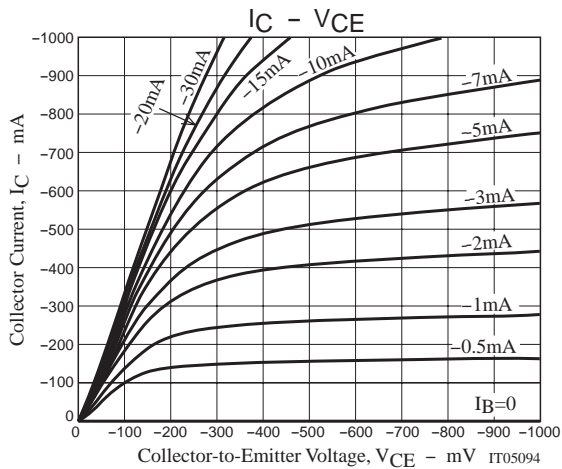
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Output Capacitance	Cob	V _{CB} = -10V, f=1MHz		6		pF
Collector-to-Emitter Saturation Voltage	V _{CE(sat)}	I _C = -400mA, I _B = -20mA		-120	-240	mV
Base-to-Emitter Saturation Voltage	V _{BE(sat)}	I _C = -400mA, I _B = -20mA		-0.9	-1.2	V
Collector-to-Base Breakdown Voltage	V _{(BR)CBO}	I _C = -10μA, I _E =0	-15			V
Collector-to-Emitter Breakdown Voltage	V _{(BR)CEO}	I _C = -1mA, R _{BE} =∞	-12			V
Emitter-to-Base Breakdown Voltage	V _{(BR)EBO}	I _E = -10μA, I _C =0	-5			V
Turn-ON Time	t _{on}	See specified Test Circuit.		30		ns
Storage Time	t _{stg}	See specified Test Circuit.		75		ns
Fall Time	t _f	See specified Test Circuit.		15		ns

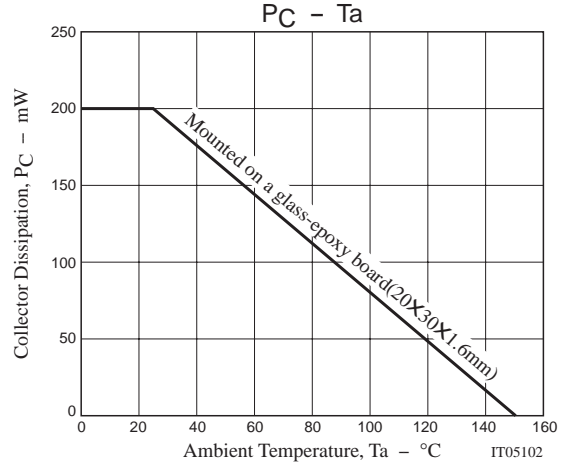
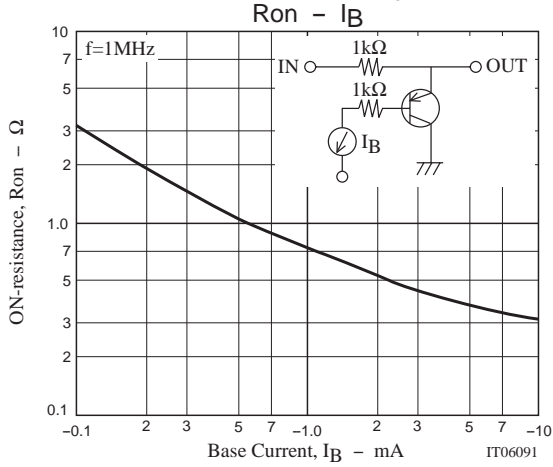
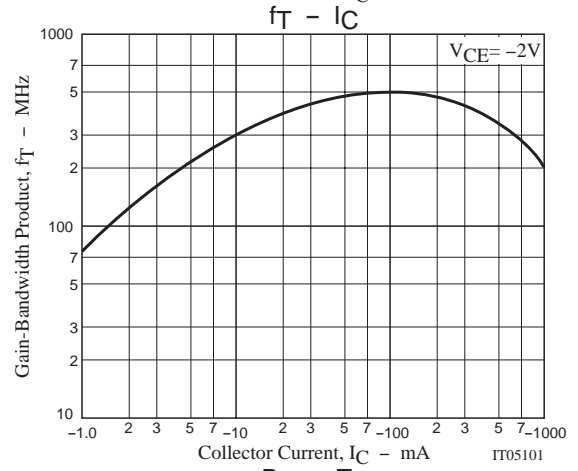
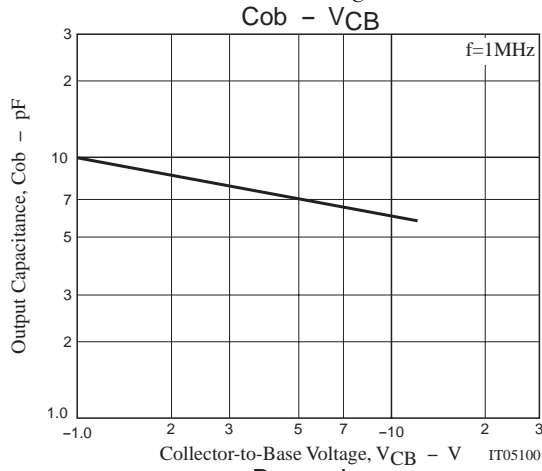
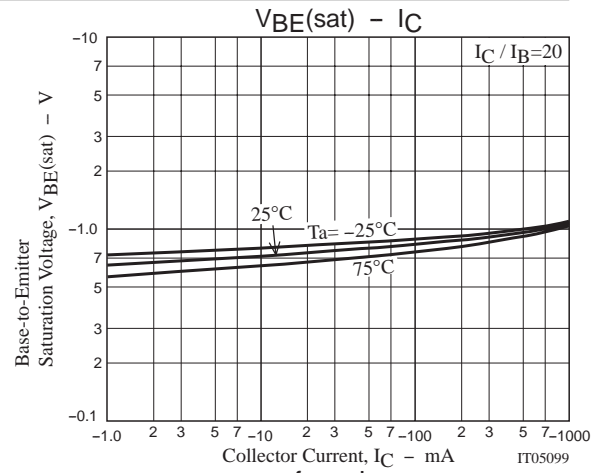
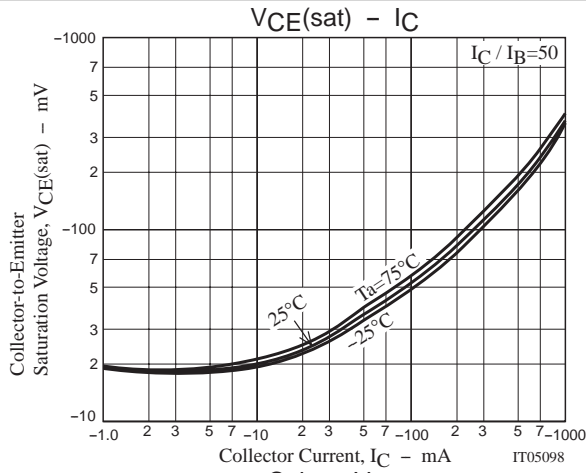
Switching Time Test Circuit



$$I_C = 20I_{B1} = -20I_{B2} = -400\text{mA}$$



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